

# **TSM2313**

## 20V P-Channel MOSFET



**SOT-23** 

#### Pin Definition:



- 1. Gate
- SourceDrain

### PRODUCT SUMMARY

V <sub>DS</sub> (V)	$R_{DS(on)}(m\Omega)$	I <sub>D</sub> (A)
	70 @ V <sub>GS</sub> = -4.5V	-3.3
-20	90 @ V <sub>GS</sub> = -2.5V	-2.0
	130 @ V <sub>GS</sub> = -1.8V	-1.0

### **Features**

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

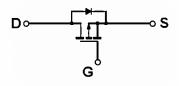
## **Application**

- Load Switch
- PA Switch

# **Ordering Information**

Part No.	Package	Packing
TSM2313CX RF	SOT-23	3Kpcs / 7" Reel

# **Block Diagram**



P-Channel MOSFET

## **Absolute Maximum Rating** (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub> -20		
Gate-Source Voltage		V <sub>GS</sub>	±12	V
Continuous Drain Current, V <sub>GS</sub> @4.5V.		l <sub>D</sub>	-3.3	Α
Pulsed Drain Current, V <sub>GS</sub> @4.5V		I <sub>DM</sub>	-20	Α
Continuous Source Current (Diode Cor	iduction) <sup>a,b</sup>	I <sub>S</sub>	-1.7	Α
Maximum Dawar Dissination	Ta = 25°C		2	W
Maximum Power Dissipation	Ta = 70°C	P <sub>D</sub>	1.3	VV
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C

## **Thermal Performance**

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	R⊖ <sub>JC</sub>	75	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	RO <sub>JA</sub>	120	°C/W

#### Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board,  $t \le 5$  sec.



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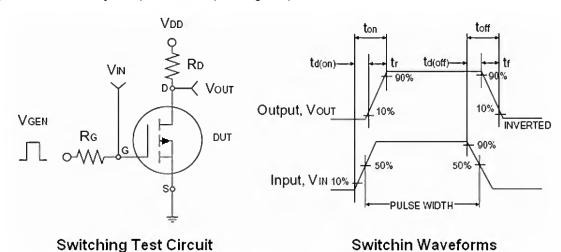


**Electrical Specifications** (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static	Static					
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250uA$	BV <sub>DSS</sub>	-20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-0.6		-1.4	V
Gate Body Leakage	$V_{GS} = \pm 12V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -20V, V_{GS} = 0V$	I <sub>DSS</sub>			-1.0	μA
On-State Drain Current <sup>a</sup>	$V_{DS} = -5V, V_{GS} = -4.5V$	I <sub>D(ON)</sub>	-15			Α
	$V_{GS} = -4.5V$ , $I_{D} = -3.3A$	R <sub>DS(ON)</sub>	55	70		
Drain-Source On-State Resistance <sup>a</sup>	$V_{GS} = -2.5V$ , $I_D = -2.0A$	R <sub>DS(ON)</sub>		70	90	mΩ
	$V_{GS} = -1.8V, I_D = -1.0A$			120	130	
Forward Transconductance <sup>a</sup>	$V_{DS} = -10V, I_{D} = -4.7A$	g <sub>fs</sub>		11		S
Diode Forward Voltage	$I_S = -1.7A$ , $V_{GS} = 0V$	$V_{SD}$		-0.8	-1.2	V
Dynamic <sup>b</sup>						
Total Gate Charge	\/ - 40\/   - 474	$Q_g$		6	9	
Gate-Source Charge	$V_{DS} = -10V, I_D = -4.7A,$ $V_{GS} = -4.5V$	$Q_{gs}$		1.4		nC
Gate-Drain Charge	V <sub>GS</sub> 4.5 V	$Q_{gd}$		1.9		1
Input Capacitance	101/11/01/	C <sub>iss</sub>		640		
Output Capacitance	$V_{DS} = -10V, V_{GS} = 0V,$	Coss		180		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		90		
Switching <sup>c</sup>						
Turn-On Delay Time	$V_{DD} = -10V, R_L = 10\Omega,$	t <sub>d(on)</sub>		22	35	
Turn-On Rise Time		t <sub>r</sub>		35	55	
Turn-Off Delay Time	$I_D = -1A$ , $V_{GEN} = -4.5V$ ,	t <sub>d(off)</sub>		45	70	nS
Turn-Off Fall Time	$R_{G} = 6\Omega$	t <sub>f</sub>		25	50	

#### Notes:

- a. pulse test: PW  $\leq 300 \mu S$ , duty cycle  $\leq 2\%$  b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.









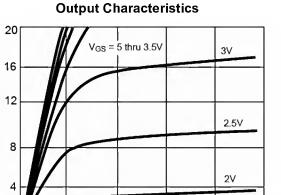


lo - Drain Current (A)

0

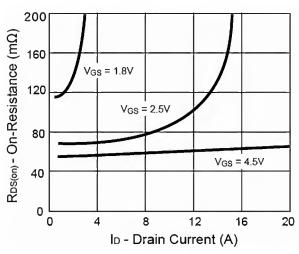
### Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

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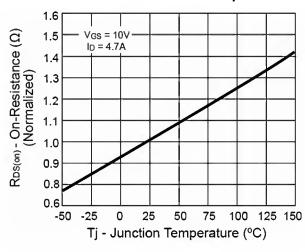


#### **On-Resistance vs. Drain Current**

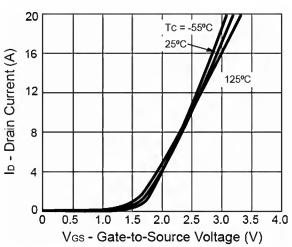
V<sub>DS</sub> - Drain-to-Source Voltage (V)



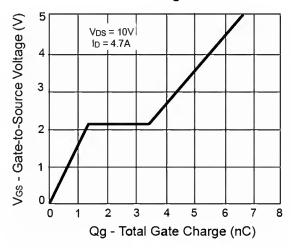
#### On-Resistance vs. Junction Temperature



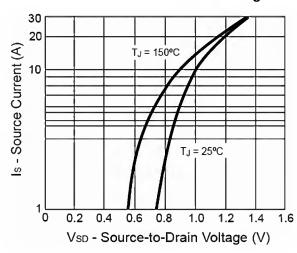
#### **Transfer Characteristics**



### **Gate Charge**



#### Source-Drain Diode Forward Voltage





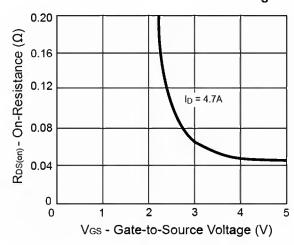


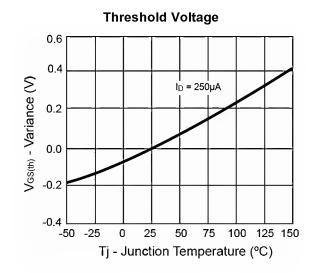




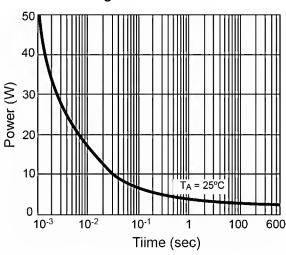
### **Electrical Characteristics Curve** (Ta = 25 °C, unless otherwise noted)

On-Resistance vs. Gate-Source Voltage

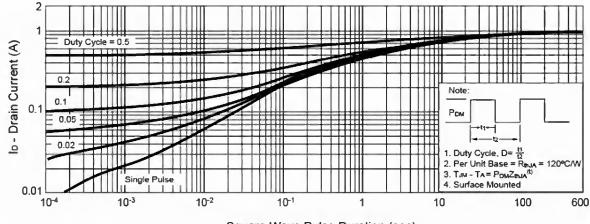




Single Pulse Power



### Normalized Thermal Transient Impedance, Junction-to-Ambient



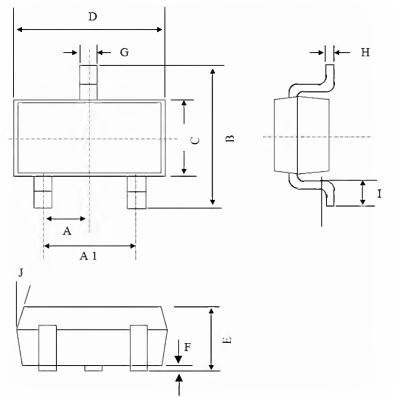
Square Wave Pulse Duration (sec)





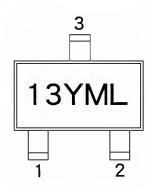


# **SOT-23 Mechanical Drawing**



SOT-23 DIMENSION						
ДІМ	MILLIMETERS		INCHES			
DIIVI	MIN	MAX	MIN	MAX.		
Α	0.95	0.95 BSC		0.037 BSC		
A1	1.9	BSC	0.074 BSC			
В	2.60	3.00	0.102	0.118		
С	1.40	1.70	0.055	0.067		
D	2.80	3.10	0.110	0.122		
E	1.00	1.30	0.039	0.051		
F	0.00	0.10	0.000	0.004		
G	0.35	0.50	0.014	0.020		
Н	0.10	0.20	0.004	0.008		
I	0.30	0.60	0.012	0.024		
J	5°	10°	5°	10°		

# **Marking Diagram**



13 = Device Code

Y = Year Code

M = Month Code

(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug,

I=Sep, J=Oct, K=Nov, L=Dec)

L = Lot Code



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